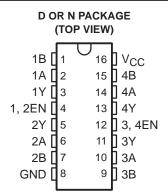
SLLS046C - JANUARY 1989 - REVISED MAY 1995

- Meets or Exceeds the Requirements of ITU Recommendations V.10, V.11, X.26, and X.27
- Designed to Operate Up To 20 Mbaud
- -7 V to 7 V Common-Mode Input Voltage Range With 300-mV Sensitivity
- 3-State TTL-Compatible Outputs
- High Input Impedance . . . 12 kΩ Min
- Input Hysteresis . . . 120 mV Typ
- Single 5-V Supply Operation
- Low Supply Current Requirement 35 mA Max
- Improved Speed and Power Consumption Compared to MC3486



description

The SN75ALS199 is a monolithic, quadruple line receiver with 3-state outputs designed using advanced, low-power, Schottky technology. This technology provides combined improvements in bar design, tooling production, and wafer fabrication, providing significantly less power consumption and permitting much higher data throughput than other designs. The device meets the specification of ITU Recommendations V.10, V.11, X.26, and X.27.

The SN75ALS199 features 3-state outputs that permit direct connection to a bus-organized system with a fail-safe design that ensures the outputs will always be high if the inputs are open. The device is optimized for balanced multipoint bus transmission at rates up to 20 megabits per second. The input features high-input impedance, input hysteresis for increased noise immunity, and an input sensitivity of ± 300 mV over a common-mode input voltage range of ± 7 V. It also features an active-high enable function for each of two receiver pairs. The SN75ALS199 is designed for optimum performance when used with the SN75ALS194 quadruple, differential line driver.

The SN75ALS199 is characterized for operation from 0°C to 70°C.

FUNCTION TABLE (each receiver)

DIFFERENTIAL INPUTS A-B	EN	OUTPUT Y
V _{ID} ≥ 0.3 V	Н	Н
-0.3 V < V _{ID} < 0.3 V	Н	?
$V_{ID} \le -0.3 V$	Н	L
X	L	Z
Open	Н	Н

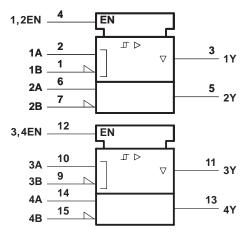
H = high level, L = low level, X = irrelevant, ? = indeterminate, Z = high impedance (off)



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

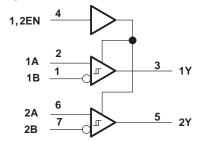


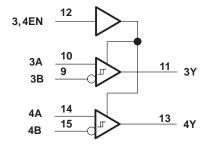
logic symbol†



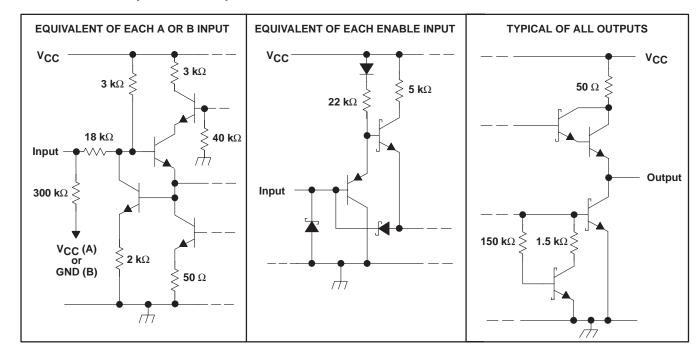
[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram





schematics of inputs and outputs



SLLS046C - JANUARY 1989 - REVISED MAY 1995

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V _{CC} (see Note 1)	
Input voltage, V _I (A or B inputs)	
Differential input voltage, V _{ID} (see Note 2)	±15 V
Enable input voltage, V _I	
Low-level output current, I _{OL}	50 mA
Continuous total dissipation	See Dissipation Rating Table
Operating free-air temperature range, T _A	0°C to 70°C
Storage temperature range, T _{stg}	– 65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. Differential input voltage is measured at the noninverting input with respect to the corresponding inverting input.

DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR	T _A = 70°C POWER RATING			
D	950 mW	7.6 mW/°C	608 mW			
N	1150 mW	9.2 mW/°C	736 mW			

recommended operating conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}	4.75	5	5.25	V
Common-mode input voltage, V _{IC}			±7	V
Differential input voltage, V _{ID}			±12	V
High-level input voltage, VIH	2			V
Low-level input voltage, V _{IL}			0.8	V
High-level output current, I _{OH}			- 400	μΑ
Low-level output current, IOL			16	mA
Operating free-air temperature, T _A	0		70	°C



NOTES: 1. All voltage values, except differential input voltage, are with respect to network ground terminal.

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electrical characteristics over recommended ranges of common-mode input voltage, supply voltage, and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDIT	TONS	MIN	TYP [†]	MAX	UNIT	
V _{IT+}	Positive-going input threshold voltage					300	mV	
VIT-	Negative-going input threshold voltage			-300‡			mV	
V _{hys}	Hysteresis voltage (V _{IT+} – V _{IT-})				120		mV	
٧ıK	Enable-input clamp voltage	$I_{I} = -18 \text{ mA}$				-1.5	V	
VOH	High-level output voltage	$V_{ID} = 300 \text{ mV},$	$I_{OH} = -400 \mu A$	2.7	3.6		V	
Vai	Low-level output voltage	V _{ID} = - 300 mV	I _{OL} = 8 mA			0.45	V	
VOL	Low-level output voltage	VID = - 300 IIIV	I _{OL} = 16 mA			0.5	l v	
107	High-impedance-state output current	$V_{IL} = 0.8 \text{ V}, V_{ID} = -3 \text{ V}, V_{O} = 2.7 \text{ V}$				20	μΑ	
loz	riign-impedance-state odiput current	$V_{IL} = 0.8 \text{ V}, V_{IO} = 3 \text{ V},$	$V_0 = 0.5 V$			-20	μΑ	
١,	Line input current	Other input at 0 V,	V _I = 15 V		0.7	1.2	mA	
11	Line input current	See Note 3	V _I = −15 V		-1	-1.7	IIIA	
ı	High-level enable-input current	VIII				20	μΑ	
ΊΗ	r light-level enable-input current		V _{IH} = 5.25 V			100	μΑ	
IլL	Low-level enable-input current	V _{IL} = 0.4 V				-100	μΑ	
	Input resistance			12	18	·	kΩ	
los	Short-circuit output current§	V _{ID} = 3 V,	VO = 0	-15	-78	-130	mA	
Icc	Supply current	Outputs disabled			22	35	mA	

[†] All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

switching characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

	PARAMETER	TEST CON	MIN	TYP	MAX	UNIT	
^t PLH	Propagation delay time, low- to high-level output	$V_{ID} = 0 V \text{ to } 3 V,$	= 0 V to 3 V, $C_L = 15 pF$,		15	22	ns
^t PHL	Propagation delay time, high- to low-level output	See Figure 2	_		15	22	115
^t PZH	Output enable time to high level	C _I = 15 pF,	See Figure 3		13	25	no
tPZL	Output enable time to low level	CL = 15 pr,	See Figure 3		11	25	ns
tPHZ	Output disable time from high level	C _I = 15 pF,	See Figure 3		13	25	no
t _{PLZ}	Output disable time from low level	CL = 15 pr,	See Figure 3		15	22	ns



[‡] The algebraic convention, in which the less positive limit is designated minimum, is used in this data sheet for threshold voltage levels only.

[§] Not more than one output should be shorted at a time, and the duration of the short circuit should not exceed one second.

NOTE 3: Refer to ITU Recommendations V.10 and V.11 for exact conditions.

PARAMETER MEASUREMENT INFORMATION

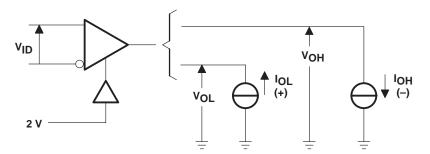
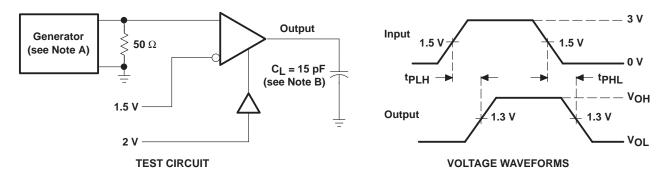


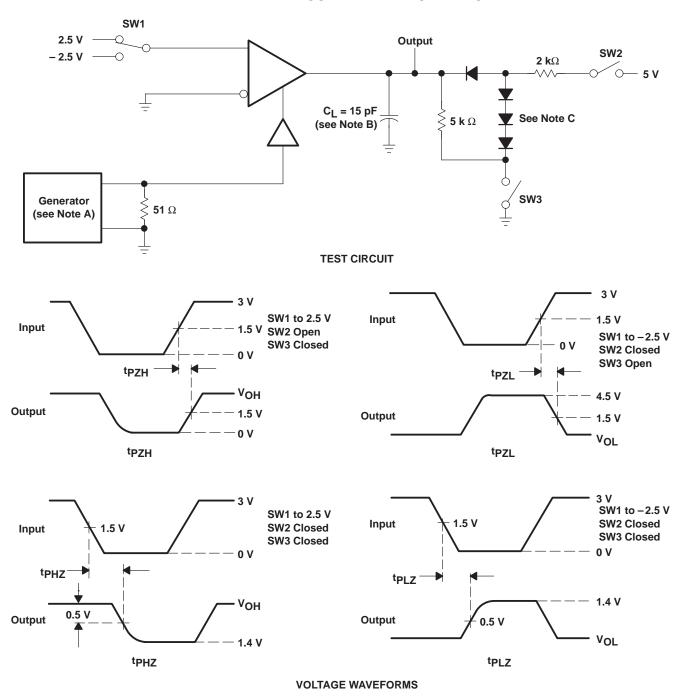
Figure 1. V_{OH} and V_{OL} Test Circuit



- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, duty cycle \leq 50%, Z_O = 50 Ω , $t_f \leq$ 6 ns, $t_f \leq$ 6 ns.
 - B. C_L includes probe and jig capacitance.

Figure 2. Test Circuit and Voltage Waveforms

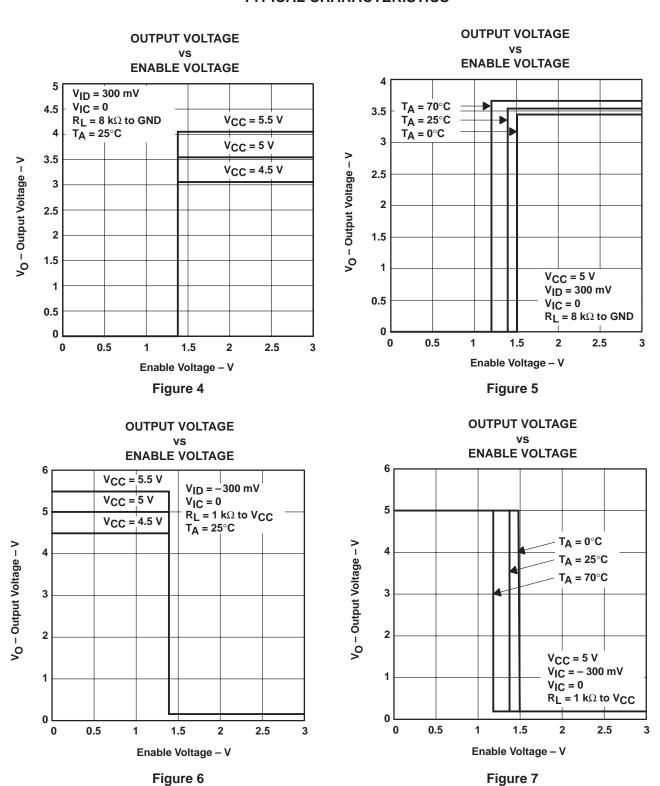
PARAMETER MEASUREMENT INFORMATION



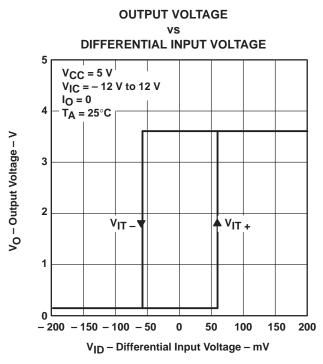
- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, duty cycle \leq 50%, Z_O = 50 Ω , $t_f \leq$ 6 ns, $t_f \leq$ 6 ns.
 - B. C_L includes probe and jig capacitance.
 - C. All diodes are 1N3064 or equivalent.

Figure 3. Test Circuit and Voltage Waveforms











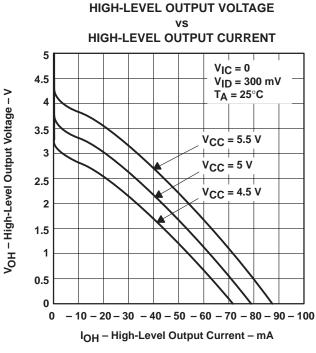


Figure 10

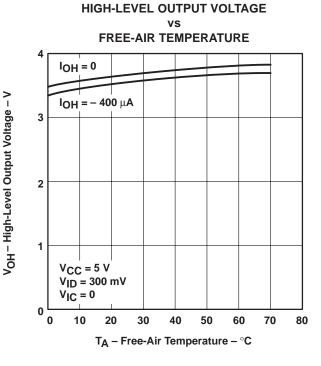


Figure 9

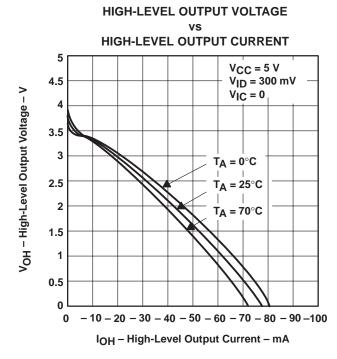


Figure 11



LOW-LEVEL OUTPUT VOLTAGE

FREE-AIR TEMPERATURE

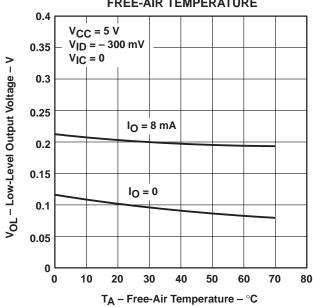


Figure 12

LOW-LEVEL OUTPUT VOLTAGE

vs

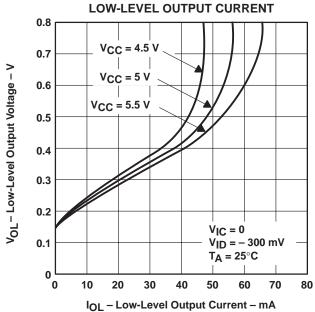


Figure 13

LOW-LEVEL OUTPUT VOLTAGE

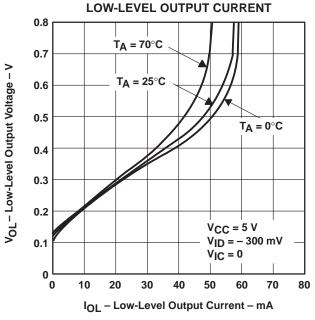


Figure 14

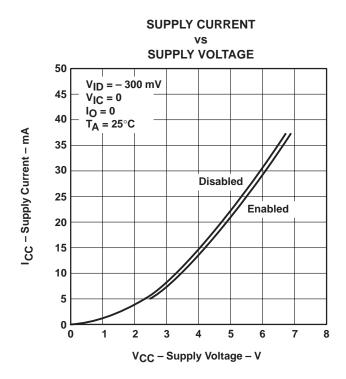


Figure 15

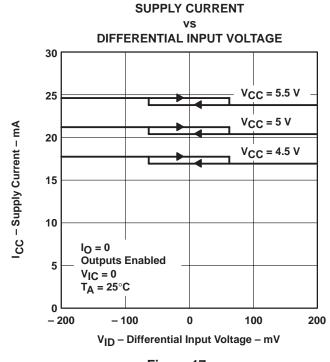


Figure 17

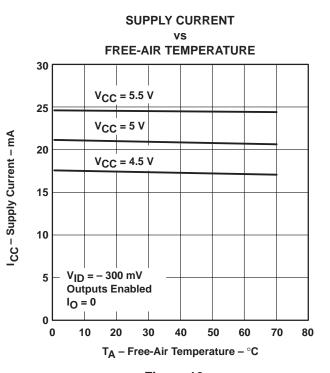
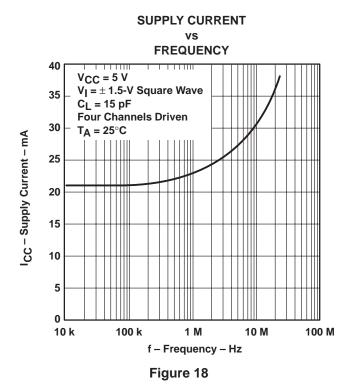
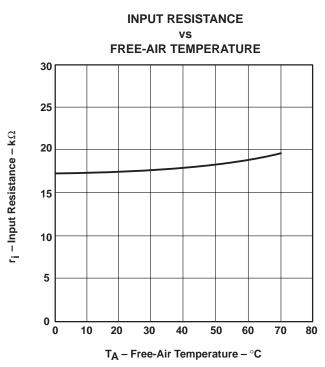


Figure 16





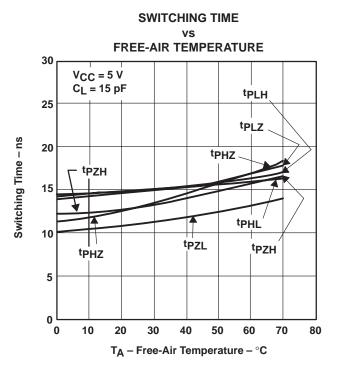
INPUT CURRENT



INPUT VOLTAGE TO GND 3 T_A = 25°C 2 - Input Current - mA 1 0 -1 - 2 -3 - 20 - 15 - 10 - 5 0 5 10 15 20 V_I - Input Voltage to GND - V

Figure 19

Figure 20



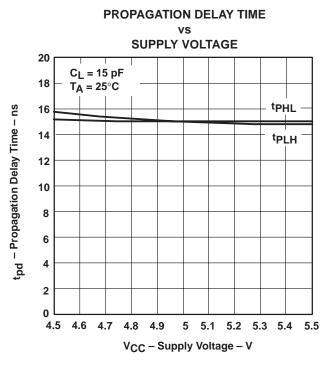


Figure 21

Figure 22



PACKAGE OPTION ADDENDUM

10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
SN75ALS199D	ACTIVE	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	75ALS199	Samples
SN75ALS199DR	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	75ALS199	Samples
SN75ALS199N	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	SN75ALS199N	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

10-Dec-2020

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device		Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN75ALS199DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1





*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
SN75ALS199DR	SOIC	D	16	2500	333.2	345.9	28.6	

D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



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